

SINGLE 2 INPUT POSITIVE OR GATE

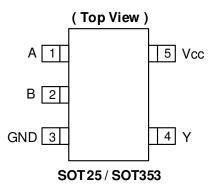
Description

The 74LVC1G32Q is an automotive-compliant, single 2-input positive OR gate with a standard push-pull output. The device is designed for operation with a power supply range of 1.65V to 5.5V. The inputs are tolerant to 5.5V allowing this device to be used in a mixed voltage environment. The device is fully specified for partial power down applications using IOFF. The IOFF circuitry disables the output preventing damaging current backflow when the device is powered down.

The gate performs the positive Boolean function:

$$Y = A + B \text{ or } Y = \overline{\overline{A} \bullet \overline{B}}$$

Pin Assignments



Features

- Grade 1 Ambient Temperature Operation: -40°C to +125°C
- Wide Supply Voltage Range from 1.65V to 5.5V
- ±24mA Output Drive at 3.3V
- CMOS Low Power Consumption
- Ioff Supports Partial-Power-Down Mode Operation
- Inputs Accept up to 5.5V Regardless of Vcc Level
- ESD Protection Tested per AEC-Q100
- Exceeds 2000V Human Body Model (AEC-Q100-002)
- Exceeds 1000V Charged Device Model (AEC-Q100-011)
- Latch-Up Exceeds 100mA (AEC-Q100-004)
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The 74LVC1G32Q is suitable for automotive applications requiring specific change control; this part is AEC-Q100 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

Applications

- Voltage Level Shifting
- General Purpose Logic
- Power Down Signal Isolation
- Wide Array of Products such as:
 - Automotive Applications within Grade 1 Temperature Range
 - Industrial Computing/Controls/Automation
 - High Reliability Networking/Communications
 - Industrial/Agricultural Equipment

Notes:

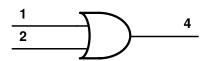
- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



Pin Descriptions

Pin Name	Description
А	Data Input
В	Data Input
GND	Ground
Y	Data Output
Vcc	Supply Voltage

Logic Diagram



Function Table

Inp	Output	
Α	В	Υ
Н	Х	Н
Х	Н	Н
L	L	L

Absolute Maximum Ratings (Notes 4 & 5)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	kV
ESD CDM	Charged Device Model ESD Protection	1	kV
V _{CC}	Supply Voltage Range	-0.5 to 6.5	٧
Vı	Input Voltage Range	-0.5 to 6.5	V
Vo	Voltage Applied to Output in High Impedance or IOFF State	-0.5 to 6.5	V
Vo	Voltage Applied to Output in High or Low State	-0.5 to Vcc +0.5	V
lık	Input Clamp Current V _I < 0	-50	mA
Іок	Output Clamp Current	-50	mA
lo	Continuous Output Current	±50	mA
ICC, IGND	Continuous Current Through Vcc or GND	±100	mA
TJ	Operating Junction Temperature	-40 to +150	°C
T _{STG}	Storage Temperature	-65 to +150	°C

Notes:

- 4. Stresses beyond the absolute maximum can result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.
- 5. Forcing the maximum allowed voltage could cause a condition exceeding the maximum current or conversely forcing the maximum current could cause a condition exceeding the maximum voltage. The ratings of both current and voltage must be maintained within the controlled range.



Recommended Operating Conditions (Note 6)

Symbol		Parameter	Min	Max	Unit
V	Operating Voltage	Operating	1.65	5.5	V
V _{CC}	Operating voltage	Data retention only	1.5	_	V
		$V_{CC} = 1.65V$ to 1.95V	0.65 × Vcc	_	
ViH	High-Level Input Voltage	Vcc = 2.3V to 2.7V	1.7	_	V
VIH	Tilgii-Level iliput voltage	$V_{CC} = 3V$ to $3.6V$	2	_	v
		$V_{CC} = 4.5V$ to $5.5V$	$0.7 \times V_{CC}$	_	
		$V_{CC} = 1.65V \text{ to } 1.95V$	_	$0.35 \times V_{\text{CC}}$	
V	Low Lovel Input Voltage	$V_{CC} = 2.3V$ to $2.7V$	_	0.7	V
VIL	Low-Level Input Voltage	$V_{CC} = 3V$ to $3.6V$	_	0.8	ď
		Vcc = 4.5V to 5.5V	_	0.3 × Vcc	
Vı	Input Voltage		0	5.5	V
Vo	Output Voltage		0	Vcc	V
		Vcc = 1.65V	_	-4	
	High-Level Output Current	Vcc = 2.3V	_	-8	mA
lau		Vcc = 2.7V	_	-12	
Іон	riigii-Level Output Guirent	Voc. 2V	_	-16	IIIA
		V _{CC} = 3V	_	-24	
		$V_{CC} = 4.5V$	_	-32	
		$V_{CC} = 1.65V$	_	4	
		$V_{CC} = 2.3V$	_	8	
lol	Low-Level Output Current	Vcc = 2.7V	_	12	mA
IOL	Low-Level Output Ourient	Vcc = 3V	_	16	111/4
		VCC = 3V	_	24	
		$V_{CC} = 4.5V$	_	32	
	looset Toomille of Discour Fall	$V_{CC} = 1.8V \pm 0.15V, 2.5V \pm 0.2V$	_	20	
Δt/ΔV	Input Transition Rise or Fall Rate	$V_{CC} = 3.3V \pm 0.3V$	_	10	ns/V
		$V_{CC} = 5V \pm 0.5V$	_	5	
Та	Operating Free-Air Temperature	_	-40	+125	°C

Note:

6. Unused inputs should be held at $\ensuremath{V_{\text{CC}}}$ or Ground.



Electrical Characteristics (All typical values are at $V_{CC} = 3.3V$, $T_A = +25$ °C)

Cumbal	Davamatav	Test Conditions		.,	-40°	C to +125°	°C	l locia
Symbol	Parameter	lest Co	nditions Vcc		Min	Тур	Max	Unit
			Іон = -100μΑ	1.65V to 5.5V	Vcc - 0.1	_	_	
			IOH = -4mA	1.65V	0.95	_	_	
\/	Lligh Lovel Output Voltage	VI = VIH or VIL	Iон = -8mA	2.3V	1.7	_	_	V
Vон	High Level Output Voltage	VI = VIH OF VIL	Iон = -12mA	2.7V	1.9	_	_	V
			Iон = -24mA	3V	2.0	_	_	
			I _{OH} = -32mA	4.5V	3.4	_	_	
			$I_{OL} = 100 \mu A$	1.65V to 5.5V	_	_	0.10	V
		w Level Output Voltage V _I = V _I H or V _I L	IoL = 4mA	1.65V	_	_	0.70	
			IoL = 8mA	2.3V	_	_	0.45	
Vol	Low Level Output Voltage		I _{OL} = 12mA	2.7V	_	_	0.60	
			I _{OL} = 24mA	3V	_	_	0.80	
			IoL = 32mA	4.5V	_	_	0.80	
lı	Input Current	V _I = 5.5V or GN	ID	0 to 5.5V	_	±0.1	±1	μΑ
loff	Power Down Leakage Current	$V_1 \text{ or } V_0 = 5.5V$		0V	_	_	±2	μA
Icc	Supply Current	V _I = 5.5V or GND I _O = 0		5.5V	_	0.1	4	μΑ
ΔΙςς	Additional Supply Current	One input at V _{CC} – 0.6V Other inputs at V _{CC} or GND		3V to 5.5V		_	500	μΑ
Cı	Input Capacitance	$V_I = GND$ to V_C	C	3.3V	_	5.0	_	pF

Package Characteristics

Symbol	Parameter	Package	Test Conditions	Min	Тур	Max	Unit
0	Thermal Resistance	SOT25	Note 7	_	184	_	°C/W
θЈА	θ _{JA} Junction-to-Ambient	SOT353	Note 7	_	385	_	
0	Thermal Resistance	ermal Resistance SOT25		_	62	_	00044
θЈС	Junction-to-Case	SOT353	Note 7	_	164	_	°C/W

Note: 7. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

Switching Characteristics

Figure 1 Typical Values at $T_A = +25$ °C and nominal voltages 1.8V, 2.5V, 2.7V, 3.3V, and 5.0V.

Parameter	From	То	Voc	T _A = -40°C to +125°C			Unit
Parameter	Input	Output	Vcc	Min	Тур	Max	Oilit
		Y	1.8V ± 0.15V	1.0	3.1	10.5	
			2.5V ± 0.2V	0.5	2.1	7.0	ns
t _{PD}	A or B		2.7V	0.5	2.5	7.0	
		3.3V ± 0.3V	0.5	2.1	6.0		
		•	5.0V ± 0.5V	0.5	1.7	5.5	

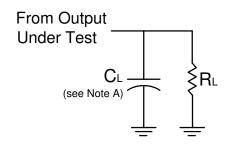
Operating Characteristics

 $T_A = +25^{\circ}C$

Parameter		Test	Vcc = 1.8V	Vcc = 2.5V	Vcc = 3.3V	Vcc = 5V	l lmia
		Conditions	Тур	Тур	Тур	Тур	Unit
CPD	Power Dissipation Capacitance	f = 10MHz	15	16	16	16	pF



Measurement Information



V _{CC}	In	puts	. V _M	CL	R∟
VCC	Vı	t _R /t _F	▼ IVI	OL .	116
1.8V ± 0.15V	V _{CC}	≤2ns	V _{CC} /2	30pF	1kΩ
2.5V ± 0.2V	Vcc	≤2ns	V _{CC} /2	30pF	500Ω
2.7V	Vcc	≤2.5ns	1.5V	50pF	500Ω
$3.3V \pm 0.3V$	3.0V	≤2.5ns	1.5V	50pF	500Ω
5.0V ± 0.5V	Vcc	≤2.5ns	V _{CC} /2	50pF	500Ω

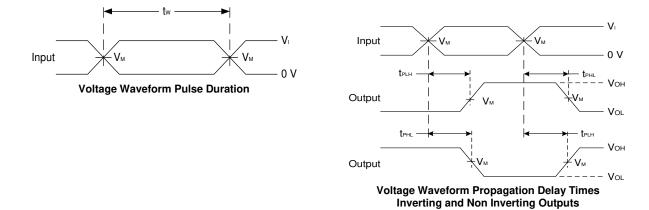


Figure 1. Load Circuit and Voltage Waveforms

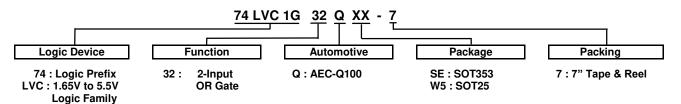
Notes: A. Includes test lead and test apparatus capacitance.

- B. All pulses are supplied at pulse repetition rate ≤ 10MHz.
- C. Inputs are measured separately one transition per measurement.
- D. t_{PLH} and t_{PHL} are the same as t_{PD} .



1G : One Gate

Ordering Information (Note 8)



Part Number	Package	Package	Package	7" Tape	and Reel	
Part Number	Code	(Notes 9 & 10)	Size	Quantity	Part Number Suffix	
74LVC1G32QSE-7	SE	SOT353	2.15mm × 2.1mm × 1.1mm 0.65mm lead pitch	3000/Tape & Reel	-7	
74LVC1G32QW5-7	W5	SOT25	3.0 mm \times 2.8 mm \times 1.2 mm 0.95 mm lead pitch	3000/Tape & Reel	-7	

8. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/. Notes:

9. Pad layout as shown in Diodes Incorporated's package outline PDFs, which can be found on our website at http://www.diodes.com/package-outlines.html.

10. The taping orientation is located on our website at https://www.diodes.com/assets/Packaging-Support-Docs/ap02007.pdf.

Marking Information

(Top View)

XXX: Identification Code : Year 0~9

: Week: A~ Z 1~ 26 week a~z 27~52 week

z represents week 52 and 53

X : A~ Z: Internal Code

SOT 25 / SOT 353

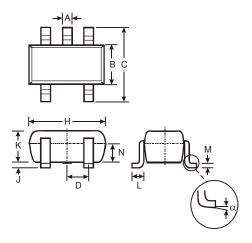
Part Number	Package	Identification Code	
74LVC1G32QW5-7	SOT25	UWQ	
74LVC1G32QSE-7	SOT353	UWQ	



Package Outline Dimensions

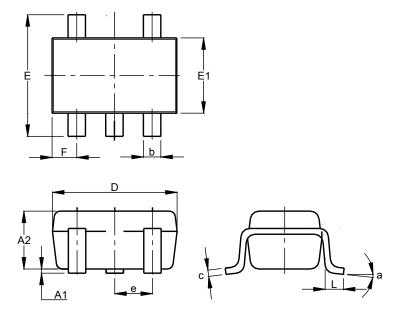
 $Please see \ http://www.diodes.com/package-outlines.html \ for \ the \ latest \ version.$

(1) Package Type: SOT25



	SOT	25	
Dim	Min	Max	Тур
Α	0.35	0.50	0.38
В	1.50	1.70	1.60
С	2.70	3.00	2.80
D	-	-	0.95
Н	2.90	3.10	3.00
J	0.013	0.10	0.05
K	1.00	1.30	1.10
L	0.35	0.55	0.40
М	0.10	0.20	0.15
N	0.70	0.80	0.75
α	0°	8°	-
All D)imensi	ons in	mm

(2) Package Type: SOT353



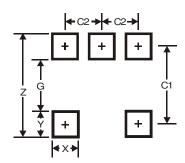
SOT353				
Dim	Min	Max	Тур	
A 1	0.00	0.10	0.05	
A2	0.90	1.00	0.95	
b	0.10	0.30	0.25	
С	0.10	0.22	0.11	
D	1.80	2.20	2.15	
Е	2.00	2.20	2.10	
E1	1.15	1.35	1.30	
е	0.650 BSC			
F	0.40	0.45	0.425	
L	0.25	0.40	0.30	
а	0°	8°		
All Dimensions in mm				



Suggested Pad Layout

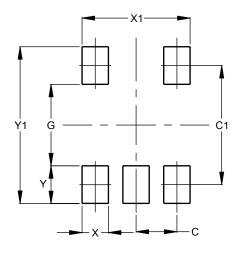
Please see http://www.diodes.com/package-outlines.html for the latest version.

(1) Package Type: SOT25



Dimensions	Value
Z	3.20
G	1.60
X	0.55
Υ	0.80
C1	2.40
C2	0.95

(2) Package Type: SOT353



Dimensions	Value (in mm)	
С	0.650	
C1	1.900	
G	1.300	
Х	0.420	
X1	1.720	
Y	0.600	
Y1	2.500	

Mechanical Data

SOT25

- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.0158 grams (Approximate)

SOT353

- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.0064 grams (Approximate)



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